# Enhancing Oxide Properties: The Approach of the Modern Alchemist

Darrell G. Schlom

Department of Materials Science and Engineering Cornell University

Kavli Institute at Cornell for Nanoscale Science

#### The Sorcerers



Craig Fennie (Cornell)

Karin Rabe (Rutgers)

# What's New? — Motivation

- Theoretical Predictions
  - Effect of Strain on Ferroelectric Properties of SrTiO<sub>3</sub>, BaTiO<sub>3</sub>, BaTiO<sub>3</sub> / SrTiO<sub>3</sub> Superlattices
  - N.A. Pertsev, A.G. Zembilgotov, and A.K. Tagantsev, *Phys. Rev. Lett.* **80**, 1988 (1998).
  - J.B. Neaton and K.M. Rabe, Appl. Phys. Lett. 82, 1586 (2003).
  - Y.L. Li and L.Q. Chen, Appl. Phys. Lett. 88, 072905 (2006).
  - Ability to Turn on Ferromagnetism in  $EuTiO_3$  with E
  - Ability to Turn on Ferroelectricity in  $EuTiO_3$  with B
  - C.J. Fennie and K.M. Rabe, Phys. Rev. Lett. 97, 267602 (2007).
  - Effect of Strain on Band Gap of SrTiO<sub>3</sub>
  - R.F. Berger, C.J. Fennie, and J.B. Neaton, *Phys. Rev. Lett.* **107**, 146804 (2011).

#### **Effect of Biaxial Strain on BaTiO<sub>3</sub>**



P.W. Forsbergh, Jr., "Effect of a Two-Dimensional Pressure on the Curie Point of Barium Titanate," *Physical Review* **93**, 686 (1954).

### Strained Silicon in MOSFETs



Photo: IBM Corporation (http://www.research.ibm.com/resources/press/strainedsilicon/)

# Biaxial Strain via Epitaxy





- Introduction
- Turning a Dielectric into a Ferroelectric Strained SrTiO<sub>3</sub>
- Turning a Dielectric into a Multiferroic Strained EuTiO<sub>3</sub>
- Conclusions
- Future Directions

#### In Collaboration with the Groups of:

**Craig J. Fennie**—*Cornell University* Karin M. Rabe—*Rutgers University* **Long-Qing Chen**—*Penn State University* **David A. Muller**—*Cornell University* **Kyle M. Shen**—*Cornell University* **Venkatraman Gopalan**—*Penn State University* **Susan Trolier-McKinstry**—*Penn State University* **Peter Schiffer**—*University of Illinois* **Ezekiel Johnston-Halperin**—*Ohio State University* **Chris Hammel**—*Ohio State University* **Xiaoqing Pan**—University of Michigan **Jeremy Levy**—University of Pittsburgh **Steven W. Kirchoefer**—*Naval Research Laboratory* **Stanislav Kamba**—Institute of Physics, Czech Republic **John Freeland**—*Argonne National Laboratory* **Phil Ryan**—Argonne National Laboratory **Jürgen Schubert**—Forschungszentrum Jülich GmbH **Jochen Mannhart**—*Max-Planck-Institute für Festkörperforschung* **Reinhard Uecker**—Leibniz Institute für Kristallzüchtung

#### **Effect of Strain on SrTiO<sub>3</sub>—Theory**



N.A. Pertsev, A.K. Tagantsev, and N. Setter, "Phase Transitions and Strain-Induced Ferroelectricity in SrTiO<sub>3</sub> Epitaxial Thin Films," *Physical Review* **61** (2000) 825-829.





#### **Effect of Strain on SrTiO<sub>3</sub>—Theory**



# Substrates are Key



### **Commercial Perovskite Substrates**



#### FLOATING ZONE (FZ) CRYSTAL GROWTH



Courtesy to Institute of Crystal Growth, Berlin

#### W.G. Pfann, 1951

Current trends in silicon crystal growth W.v.Ammon

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#### FIRST 200 mm FZ CRYSTAL



Current trends in silicon crystal growth W.v.Ammon

#### Floating-Zone Growth of ReScO<sub>3</sub>

- Grew Single Crystals of  $DyScO_3 (a \approx 3.94 \text{ Å})$   $GdScO_3 (a \approx 3.97 \text{ Å})$   $SmScO_3 (a \approx 3.99 \text{ Å})$  $NdScO_3 (a \approx 4.01 \text{ Å})$
- All Melt Congruently  $T_m \sim 2100 \ ^{\circ}\text{C}$

Jochen Mannhart's Group University of Augsburg



### **Commercial Perovskite Substrates**



# The Sorcerer's Apprentice

RHEED, QCM, MOSS, BandiT + ARPES, XPS, LEED

# Oxide MBE Group



# **MBE** ≈ Atomic Spray Painting





#### **Strain-Enhanced SrTiO<sub>3</sub>**



M.D. Biegalski, Y. Jia, D.G. Schlom, S. Trolier-McKinstry, S.K. Streiffer, V. Sherman, R. Uecker, and P. Reiche, *Applied Physics Letters* **88** (2006) 192907. J.H. Haeni, P. Irvin, W. Chang, R. Uecker, P. Reiche, Y.L. Li, S. Choudhury, W. Tian, M.E. Hawley,
B. Craigo, A.K. Tagantsev, X.Q. Pan, S.K. Streiffer, L.Q. Chen, S.W. Kirchoefer, J. Levy, and D.G. Schlom, *Nature* 430 (2004) 758-761.

# 250 Å SrTiO<sub>3</sub> on (110) DyScO<sub>3</sub> vs. GdScO<sub>3</sub>

#### **SrTiO<sub>3</sub> / DyScO<sub>3</sub> ~ 1.0%**

#### **SrTiO<sub>3</sub> / GdScO<sub>3</sub> ~ 1.6%**



Strain shifts  $T_C$ 

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#### **SrTiO<sub>3</sub> / GdScO<sub>3</sub> ~ 1.6%**



Strain shifts  $T_C$ 

#### **Effect of Strain on SrTiO<sub>3</sub>—Theory**



#### Commensurate when Thin (<~10 ML)

#### 5 ML SrTiO<sub>3</sub>/Si





#### SrTiO<sub>3</sub> 202 reflection



M.P. Warusawithana, C. Cen, C.R. Sleasman, J.C. Woicik, Y.L. Li, L. Fitting Kourkoutis, J.A. Klug, H. Li, P. Ryan, L-P. Wang, M. Bedzyk, D.A. Muller, L.Q. Chen, J. Levy, and D.G. Schlom, "A Ferroelectric Oxide Made Directly on Silicon," *Science* **324** (2009) 367-370.

David Muller—*Cornell University* 

Joseph Woicik—*NIST* 

# 20 Å Thick SrTiO<sub>3</sub> / (100) Si



M.P. Warusawithana, C. Cen, C.R. Sleasman, J.C. Woicik, Y.L. Li, L. Fitting Kourkoutis, J.A. Klug, H. Li, P. Ryan, L-P. Wang, M. Bedzyk, D.A. Muller, L.Q. Chen, J. Levy, and D.G. Schlom, "A Ferroelectric Oxide Made Directly on Silicon," *Science* 324 (2009) 367-370.



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### **Ferromagnetic Ferroelectrics**



#### Mind the Units!





H.W. Jang, S.H. Baek, D. Ortiz, C.M. Folkman, C.B. Eom,
Y.H. Chu, P. Shafer, R. Ramesh, V. Vaithyanathan, and
D.G. Schlom, "Epitaxial (001) BiFeO<sub>3</sub> Membranes with
Substantially Reduced Fatigue and Leakage,"
Applied Physics Letters 92 (2008) 062910

T. Kimura, T. Goto, H. Shintani, K. Ishizaka1, T. Arima, and Y. Tokura, "Magnetic Control of Ferroelectric Polarization," *Nature* **426** (2003) 55-58.

### **Ferromagnetic Ferroelectrics**



#### Spin-Phonon Coupling—Route to Phase Control



With control parameter take  $\omega_0 = 0 \implies \omega^2 \propto -\langle \mathbf{S}_i \cdot \mathbf{S}_j \rangle$ 

$$\mathsf{AFM} \to \langle S_i \cdot S_j \rangle = -1$$

Stable phonon



→ Antiferromagnetic, Paraelectric

 $\mathsf{FM} \to \langle S_i \cdot S_j \rangle = +1$ 

**Unstable phonon** 



→ Ferromagnetic, Ferroelectric

Leads to a FM-FE state competing with the AFM-PE ground state



# **Bulk EuTiO<sub>3</sub> (unstrained)**

PHYSICAL REVIEW B, VOLUME 64, 054415

#### Coupling between magnetism and dielectric properties in quantum paraelectric EuTiO<sub>3</sub>

T. Katsufuji and H. Takagi

Department of Advanced Materials Science, University of Tokyo, Tokyo 113-8656, Japan and Core Research for Evolutional Science and Technology (CREST), Japan Science and Technology Corporation, Japan





#### **Strained EuTiO<sub>3</sub>—a Ferroelectric Ferromagnet?**





C.J. Fennie and K.M. Rabe, "Magnetic and Electric Phase Control in Epitaxial EuTiO<sub>3</sub> from First Principles," *Physical Review Letters* **97** (2006) 267602.

#### **Strained EuTiO<sub>3</sub>—a Ferroelectric Ferromagnet?**





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# Effect of Strain on EuTiO<sub>3</sub>



# **Commercial Perovskite Substrates**



#### First Principles Epitaxial Phase Diagram of Strained EuTiO<sub>3</sub> (at T = 0 K)



#### **EuTiO<sub>3</sub> / SrTiO<sub>3</sub> by PLD shows Expanded Lattice Constant**



FIG. 4. Rod scan through the (001) Bragg peak of  $SrTiO_3$  and finitethickness broadened thin-film "Bragg" peak. Solid line is a simple model calculation consisting of a resolution-limited STO Bragg peak and a simple finite-size line shape for the ETO film.

H.-H. Wang, A. Fleet, J.D. Brock, D. Dale, and Y. Suzuki, *J. Appl. Phys.* **96**, 5324 (2004).



Fig. 2. Out-of-plane XRD patterns for thin films grown under  $P_{O2} = 1.0 \times 10^{-4}$  Pa (a),  $1.0 \times 10^{-5}$  Pa (b), and  $1.0 \times 10^{-6}$  Pa (c).

K. Kugimiya, K. Fujita, K. Tanaka, and K. Hirao, J. Magn. Magn. Mater. **310**, 2268 (2007).



Fig. 3 X-ray diffraction pattern of EuTiO<sub>3</sub> thin films grown on SrTiO<sub>3</sub> (001), LSAT (001), LaSrGaO<sub>4</sub> (001), and LaAlO<sub>3</sub> (001) single-crystal substrates

S. C. Chae, Y. J. Chang, D.-W. Kim,
B. W. Lee, I. Choi, and C. U. Jung, *J. Electroceram.* 22, 216 (2009).

# But EuTiO<sub>3</sub> and SrTiO<sub>3</sub> are perfectly lattice-matched, so no expanded out-of-plane lattice constant expected!

#### **EuTiO<sub>3</sub> / SrTiO<sub>3</sub> by PLD shows Ferromagnetism**



Fig. 3. Temperature dependence of magnetization for the film grown under  $P_{O2} = 1.0 \times 10^{-6}$  Pa (closed circles). For comparison, data for bulk EuTiO<sub>3</sub> specimen prepared by solid-state reaction, which are magnified by a factor of 10, are also shown (open triangles). The inset shows the dependence of magnetization at 2 K on external magnetic field.

K. Kugimiya, K. Fujita, K. Tanaka, and K. Hirao, J. Magn. Magn. Mater. **310**, 2268 (2007).



S. C. Chae, Y. J. Chang, D.-W. Kim, B. W. Lee, I. Choi, and C. U. Jung, *J. Electroceram.* **22**, 216 (2009).

But EuTiO<sub>3</sub> and SrTiO<sub>3</sub> are perfectly lattice-matched, so no expanded lattice constants or ferromagnetism are expected!

### **SrTiO<sub>3</sub> / SrTiO<sub>3</sub> by PLD shows Expanded Lattice and Ferroelectricity**





E.J. Tarsa, E.A. Hachfeld, F.T. Quinlan, J.S. Speck, and M. Eddy, *Appl. Phys. Lett.* **68**, 490 (1996).







T. Ohnishi, M. Lippmaa, T. Yamamoto, S. Meguro, and H. Koinuma, *Appl. Phys. Lett.* **87**, 2419191 (2005).

Y. S. Kim, D.J. Kim, T.H. Kim, T.W. Noh, J.S. Choi ,B.H. Park, and J.-G. Yoon, *Appl. Phys. Lett.* **91**, 042908 (2007).

But homoepitaxial SrTiO<sub>3</sub> is perfectly lattice-matched, so no extended lattice constants or ferroelectricity are expected!

### Unstrained EuTiO<sub>3</sub> Control Samples



#### **Reactive Molecular-Beam Epitaxy**



• Sources: Eu metal Ti metal O<sub>2</sub> gas

•  $T_{\rm sub} \approx 650$  °C

•  $P_{O_2} \approx 3 \times 10^{-8}$  Torr

•  $v_{\text{growth}} \approx 0.1 \text{ Å/s}$ 

#### EuTiO<sub>3</sub> / (001) SrTiO<sub>3</sub> by MBE is ~Intrinsic



# Biaxial Strain via Epitaxy



#### 22 nm Thick (001) EuTiO<sub>3</sub> / (001) LSAT



# Biaxial Strain via Epitaxy



#### 22 nm Thick (001) EuTiO<sub>3</sub> / (110) DyScO<sub>3</sub>



#### **STEM of 22 nm EuTiO<sub>3</sub> / DyScO<sub>3</sub>**



#### SHG of Strained EuTiO<sub>3</sub> / (110) DyScO<sub>3</sub>



# Magnetic Properties of Strained EuTiO<sub>3</sub> / (110) DyScO<sub>3</sub>



J.H. Lee, L. Fang, E. Vlahos, X. Ke, Y.W. Jung, L. Fitting Kourkoutis, J-W. Kim, P.J. Ryan, T. Heeg, M. Roeckerath, V. Goian, M. Bernhagen, R. Uecker, P.C. Hammel, K.M. Rabe, S. Kamba, J. Schubert, J.W. Freeland, D.A. Muller, C.J. Fennie, P. Schiffer, V. Gopalan, E. Johnston-Halperin, and D.G. Schlom, *Nature* 466 (2010) 954-958.

# Magnetic Properties of Strained EuTiO<sub>3</sub>/DyScO<sub>3</sub> vs. DyScO<sub>3</sub>



Peter Schiffer—Penn State University (now University of Illinois)

#### First Principles Epitaxial Phase Diagram of Strained EuTiO<sub>3</sub> (at T = 0 K)



J.H. Lee, L. Fang, E. Vlahos, X. Ke, Y.W. Jung, L. Fitting Kourkoutis, J-W. Kim, P.J. Ryan, T. Heeg, M. Roeckerath, V. Goian, M. Bernhagen, R. Uecker, P.C. Hammel, K.M. Rabe, S. Kamba, J. Schubert, J.W. Freeland, D.A. Muller, C.J. Fennie, P. Schiffer, V. Gopalan, E. Johnston-Halperin, and D.G. Schlom, *Nature* 466 (2010) 954-958.

### First Principles of Straine





Biaxial Strain (%),  $\varepsilon_s$ 

# **EuTiO<sub>3</sub> Conclusions**

- Strained EuTiO<sub>3</sub> Results vs. Theory
  - Unstrained EuTiO<sub>3</sub> has Intrinsic Properties
  - Effect of Strain and Magnetic Field on Soft Modes
  - Ferroelectricity
  - ➢ Ferromagnetism ✓
  - > Ability to Turn on *M* with *E*
  - > Ability to Turn on *P* with *H*

### Conclusions

- The Properties of Oxides can be Enhanced using Strain
  - $\succ$  Enhance Ferroelectric  $T_{\rm C}$
  - $\succ$  Enhance Ferroelectric  $P_s$
  - > Turn on Ferroelectricity and Ferromagnetism
  - > Alter Bandgap and Band Lineup of Photocatalysts
  - Create Tunable Dielectrics with Highest Figure of Merit of any Known Material in GHz Regime